ap	plication	UC1856
	INFO	UC2856
	available	UC3856

# Improved Current Mode PWM Controller

### FEATURES

- Pin-for-Pin Compatible With the UC3846
- 65ns Typical Delay From Shutdown to Outputs, and 50ns Typical Delay From Sync to Outputs
- Improved Current Sense Amplifier With Reduced Noise Sensitivity
- Differential Current Sense with 3V Common Mode Range
- Trimmed Oscillator Discharge Current for Accurate Deadband Control
- Accurate 1V Shutdown Threshold
- High Current Dual Totem Pole Outputs (1.5A peak)
- TTL Compatible Oscillator SYNC Pin Thresholds
- 4kV ESD Protection

#### **BLOCK DIAGRAM**

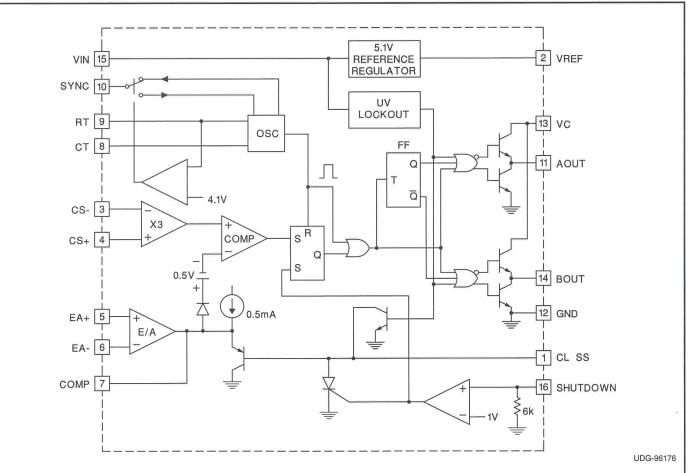
### DESCRIPTION

The UC3856 is a high performance version of the popular UC3846 series of current mode controllers, and is intended for both design upgrades and new applications where speed and accuracy are important. All input to output delays have been minimized, and the current sense output is slew rate limited to reduce noise sensitivity. Fast 1.5A peak output stages have been added to allow rapid switching of power FETs.

A low impedance TTL compatible sync output has been implemented with a tri-state function when used as a sync input.

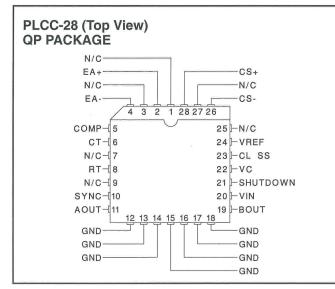
Internal chip grounding has been improved to minimize internal "noise" caused when driving large capacitive loads. This, in conjunction with the improved differential current sense amplifier results in enhanced noise immunity.

Other features include a trimmed oscillator current (8%) for accurate frequency and dead time control; a 1V, 5% shutdown threshold; and 4kV minimum ESD protection on all pins.

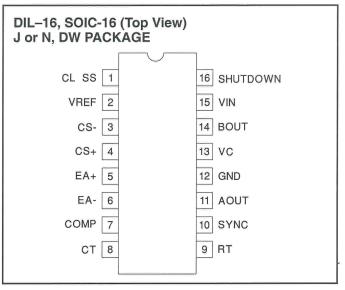


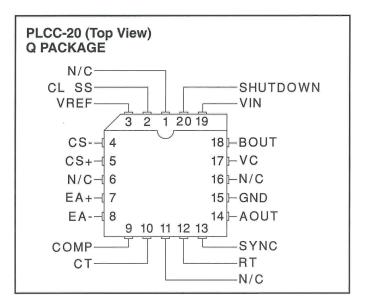
#### ABSOLUTE MAXIMUM RATINGS

Supply Voltage+40V Collector Supply Voltage+40V Output Current, Source or Sink	
DC	
Pulse (0.5µs)	
Error Amp Inputs –0.3V to +VIN	
Shutdown Input	
Current Sense Inputs0.3V to +3V	
SYNC Output Current	
Error Amplifier Output Current5mA	
Soft Start Sink Current	
Oscillator Charging Current 5mA	
Power Dissipation at $T_A = 25^{\circ}C$ (Note 2) 1000mW	
Power Dissipation at $T_C = 25^{\circ}C$ (Note 2) 2000mW	
Junction Temperature55°C to +150°C	
Storage Temperature Range65°C to +150°C	
Lead Temperature (Soldering, 10 sec.)+300°C	
All voltages are with respect to Ground. Currents are positive	
into, negative out of the specified terminal. Consult packaging	
section of databook for thermal limitations and considerations	
of package.	



#### **CONNECTION DIAGRAMS**





**ELECTRICAL CHARACTERISTICS:** Unless otherwise stated, these specifications apply for  $T_A = -55^{\circ}C$  to  $+125^{\circ}C$  for UC1856;  $-40^{\circ}C$  to  $+85^{\circ}C$  for the UC2856; and  $0^{\circ}C$  to  $+70^{\circ}C$  for the UC3856, VIN = 15V, RT = 10k, CT = 1nF,  $T_A = T_J$ .

		UC	1856/UC	2856	UC3856			
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Reference Section								
Output Voltage	$T_{\rm J} = 25^{\circ} {\rm C}, \ {\rm I}_{\rm O} = 1 {\rm mA}$	5.05	5.10	5.15	5.00	5.10	5.20	V
Line Regulation	VIN = 8V to 40V			20			20	mV
Load Regulation	$I_0 = -1mA$ to $-10mA$			15			15	mV
Total Output Variation	Line, Load, and Temperature	5.00		5.20	4.95		5.25	V
Output Noise Voltage	$10Hz < f < 10kHz, T_J = 25^{\circ}C$		50			50		μV
Long Term Stability	T <sub>J</sub> = 125°C, 1000 Hrs (Note 2)		5	25		5	25	mV
Short Circuit Current	VREF = 0V	-25	-45	-65	-25	-45	-65	mA -
Oscillator Section								
Initial Accuracy	$T_J = 25^{\circ}C$	180	200	220	180	200	220	kHz
	Over Operating Range	170		230	170		230	kHz

**ELECTRICAL CHARACTERISTICS:** Unless otherwise stated, these specifications apply for  $T_A = -55^{\circ}C$  to  $+125^{\circ}C$  for UC1856;  $-40^{\circ}C$  to  $+85^{\circ}C$  for the UC2856; and  $0^{\circ}C$  to  $+70^{\circ}C$  for the UC3856, VIN = 15V, RT = 10k, CT = 1nF,  $T_A = T_J$ .

		UC	1856/UC	2856		UC3856	5	
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Oscillator Section (cont.)		Probatic (F) (1		Constraint and a second				
Voltage Stability	VIN = 8V to 40V			2			2	%
Discharge Current	$T_{J} = 25^{\circ}C, V_{CT} = 2V$	7.5	8.0	8.8	7.5	8.0	8.8	mA
	$V_{CT} = 2V$	6.7	8.0	8.8	6.7	8.0	8.8	mA
Sync Output High Level	$I_0 = -1 \text{mA}$	2.4	3.6		2.4	3.6		V
Sync Output Low Level	$I_0 = +1 \text{mA}$		0.2	0.4		0.2	0.4	V
Sync Input High Level	CT = 0V, RT = VREF	2.0	1.5		2.0	1.5		V
Sync Input Low Level	CT = 0V, RT = VREF		1.5	0.8		1.5	0.8	V
Sync Input Current	CT = 0V, RT = VREF V <sub>SYNC</sub> = 5V		1	10		1	10	μA
Sync Delay to Outputs	CT = 0V, RT = VREF V <sub>SYNC</sub> = 0.8V to 2V		50	100		50	100	ns
Error Amplifier Section							h	
Input Offset Voltage	$V_{CM} = 2V$			5			10	mV
Input Bias Current				-1			-1	μA
Input Offset Current				500			500	nA
Common Mode Range	VIN = 8V to 40V	0		VIN-2	0		VIN-2	V
Open Loop Gain	V <sub>O</sub> = 1.2V to 3V	80	100		80	100		dB
Unity Gain Bandwidth	T <sub>J</sub> = 25°C	1	1.5		1	1.5		MHz
CMRR	$V_{CM} = 0V$ to 38V, VIN = 40V	75	100		75	100		dB
PSRR	VIN = 8V to 40V	80	100		80	100		dB
Output Sink Current	$V_{ID} = -15 \text{mV}, V_{COMP} = 1.2 \text{V}$	5	10		5	10		mA
Output Source Current	$V_{ID} = 15 mV, V_{COMP} = 2.5 V$	-0.4	-0.5		-0.4	-0.5		mA
Output High Level	$V_{ID} = 50 \text{mV}, \text{R}_{L} (\text{COMP}) = 15 \text{k}$	4.3	4.6	4.9	4.3	4.6	4.9	V
Output Low Level	$V_{ID} = -50 \text{mV}, \text{R}_{L} (\text{COMP}) = 15 \text{k}$		0.7	1		0.7	1	V
Current Sense Amplifier Section								
Amplifier Gain	V <sub>CS</sub> – = 0V, CL SS Open (Notes 3,4)	2.5	2.75	3.0	2.5	2.75	3.0	V/V
Maximum Differential Input Signal (V <sub>CS</sub> + - V <sub>CS</sub> –)	CL SS Open (Note 3) R <sub>L</sub> (COMP) = 15k	1.1	1.2		1.1	1.2		V
Input Offset Voltage	V <sub>CL SS</sub> = 0.5VCOMP Open (Note 3)		5	35		5	35	mV
CMRR	$V_{CM} = 0V$ to $3V$	60			60			dB
PSRR	VIN = 8V to 40V	60			60			dB
Input Bias Current	V <sub>CL SS</sub> = 0.5V, COMP Open (Note 3)	≍1		1	-1		1	μA
Input Offset Current	V <sub>CL SS</sub> = 0.5V, COMP Open (Note 3)	-1		1	-1		1	μΑ
Input Common Mode Range		0		3	0		3	V
Delay to Outputs	$V_{EA}$ + = VREF, EA- = 0V CS+ - CS- = 0V to 1.5V		120	250		120	250	ns
Current Limit Adjust Section					-			
Current Limit Offset	$V_{CS}$ -= 0V $V_{CS}$ += 0V, COMP = Open (Note 3)	0.43	0.5	0.57	0.43	0.5	0.57	V
Input Bias Current	$V_{EA}$ + = VREF, $V_{EA}$ - = 0V		-10	-30		-10	-30	μA
Shutdown Terminal Section								
Threshold Voltage		0.95	1.00	1.05	0.95	1.00	1.05	V
Input Voltage Range		0		5	0		5	V

		UC	1856/UC	2856		UC3856		
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Shutdown Terminal Section (cont	.)				_			
Minimum Latching Current (IcL ss)	(Note 5)	3	1.5		3	1.5		mA
Maximum Non-Latching Current (IcL ss)	(Note 6)		1.5	0.8		1.5	0.8	mA
Delay to Outputs	$V_{SHUTDOWN} = 0$ to 1.3V		65	110		65	110	ns
Output Section								
Collector-Emitter Voltage		40			40			V
Off-State Bias Current	VC = 40V			250			250	μA
Output Low Level	$I_{OUT} = 20 \text{mA}$		0.1	0.5		0.1	0.5	V
	I <sub>OUT</sub> = 200mA		0.5	2.6		0.5	2.6	V
Output High Level	$I_{OUT} = -20 \text{mA}$	12.5	13.2		12.5	13.2		V
	$I_{OUT} = -200 \text{mA}$	12	13.1		12	13.1		V
Rise Time	C1 = 1nF		40	80		40	80	ns
Fall Time	C1 = 1nF		40	80		40	80	ns
UVLO Low Saturation	$VIN = 0V$ , $I_{OUT} = 20mA$		0.8	1.5		0.8	1.5	V
PWM Section								
Maximum Duty Cycle		45	47	50	45	47	50	%
Minimum Duty Cycle				0			0	%
Undervoltage Lockout Section				1				
Startup Threshold		·	7.7	8.0		7.7	8.0	V
Threshold Hysterisis			0.7			0.7		V
Total Standby Current								
Supply Current			18	23		18	23	mA

**ELECTRICAL CHARACTERISTICS:** Unless otherwise stated, these specifications apply for  $T_A = -55^{\circ}C$  to  $+125^{\circ}C$  for UC1856;  $-40^{\circ}C$  to  $+85^{\circ}C$  for the UC2856; and  $0^{\circ}C$  to  $+70^{\circ}C$  for the UC3856, VIN = 15V, RT = 10k, CT = 1nF,  $T_A = T_J$ .

Note 1: All voltages are with respect to GND. Currents are positive into, negative out of the specified terminal.

Note 2: This parameter, although guaranteed over the recommended operating conditions is not 100% tested in production.

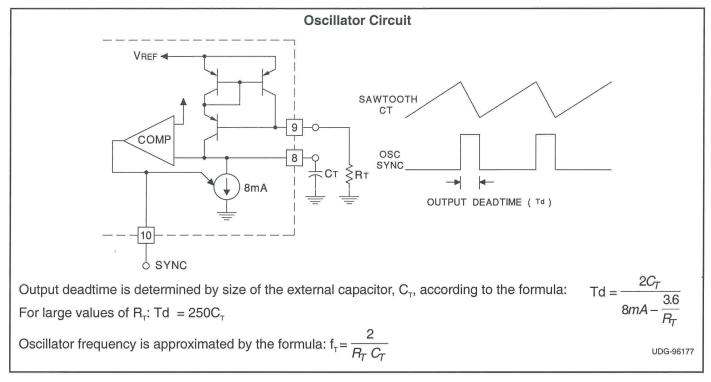
Note 3: Parameter measured at trip point of latch with  $V_{EA+} = VREF$ ,  $V_{EA-} = 0V$ .

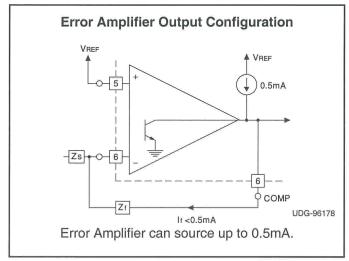
Note 4: Amplifier gain defined as:

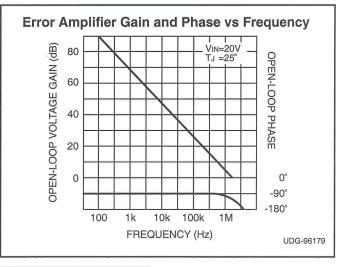
$$G = \frac{\Delta V_{COMP}}{\Delta V_{CS}}; \quad \Delta V_{CS} = 0VTO1.0V$$

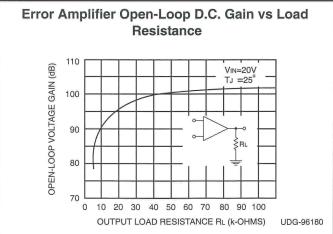
Note 5: Current into CL SS guaranteed to latch circuit into shutdown state. Note 6: Current into CL SS guaranteed not to latch circuit into shutdown state.

### **APPLICATIONS INFORMATION**

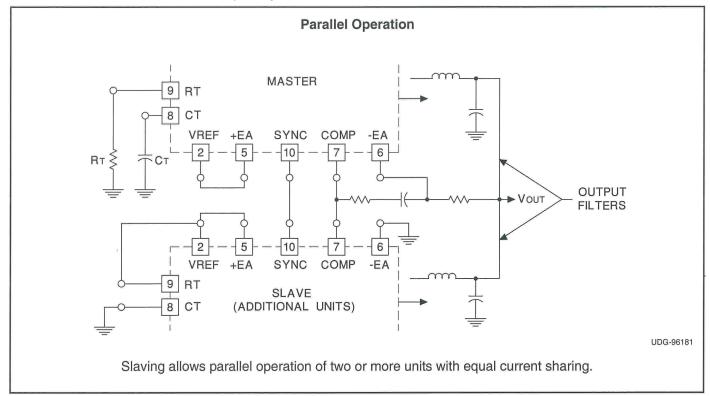


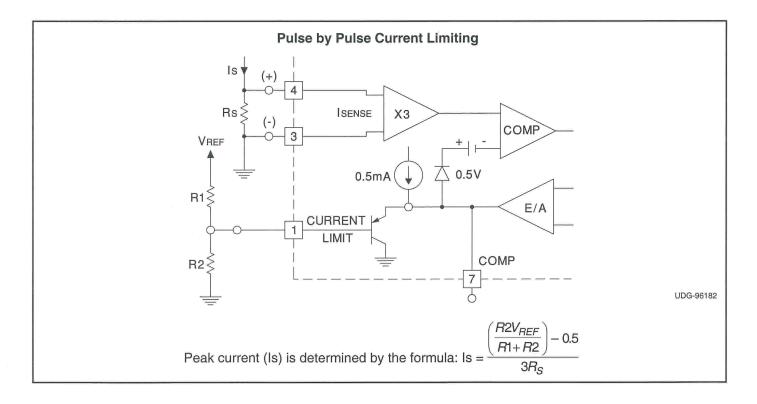




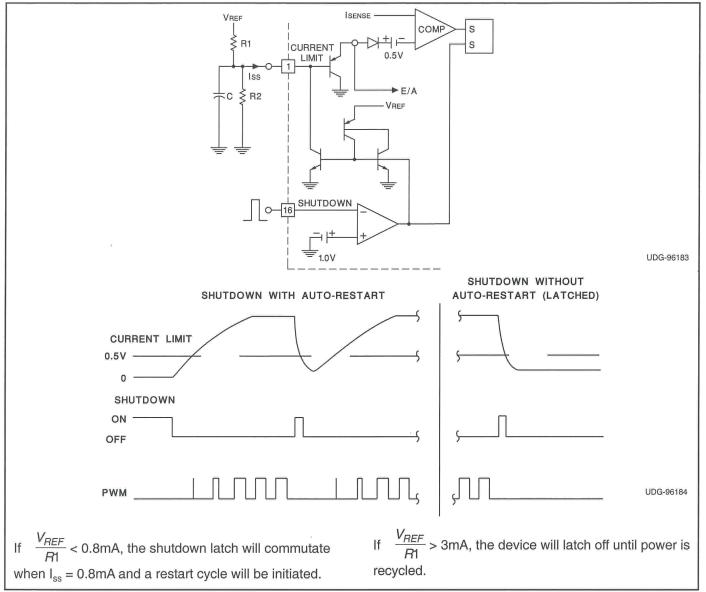


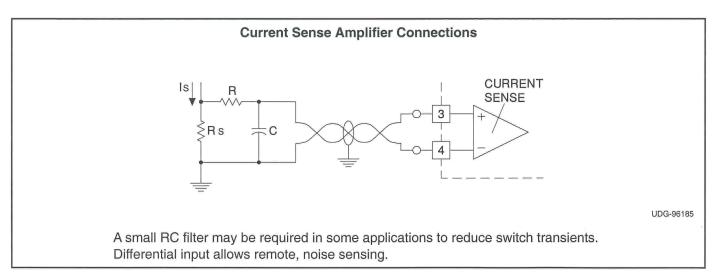
#### **APPLICATIONS INFORMATION (cont.)**



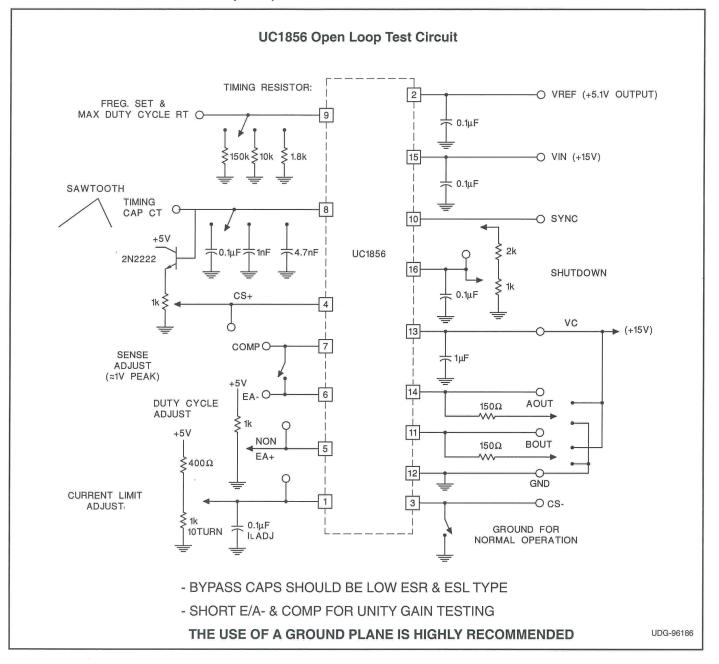


### **APPLICATIONS INFORMATION (cont.)**





#### **APPLICATIONS INFORMATION (cont.)**





### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9453001M2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9453001M2A UC1856L20/ 883B	Samples
5962-9453001MEA	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9453001ME A UC1856J/883B	Samples
UC1856J	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	UC1856J	Samples
UC1856J883B	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9453001ME A UC1856J/883B	Samples
UC1856L20	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	UC1856L20	Samples
UC1856L20883B	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9453001M2A UC1856L20/ 883B	Samples
UC2856DW	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2856DW	Samples
UC2856DWG4	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2856DW	Samples
UC2856DWTR	ACTIVE	SOIC	DW	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2856DW	Samples
UC2856DWTRG4	ACTIVE	SOIC	DW	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2856DW	Samples
UC2856J	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-40 to 85	UC2856J	Samples
UC2856N	ACTIVE	PDIP	Ν	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	UC2856N	Samples
UC2856NG4	ACTIVE	PDIP	N	16	25	TBD	Call TI	Call TI	-40 to 85		Samples
UC3856DW	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3856DW	Samples
UC3856DWTR	ACTIVE	SOIC	DW	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3856DW	Samples



Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
UC3856N	ACTIVE	PDIP	Ν	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	UC3856N	Samples
UC3856NG4	ACTIVE	PDIP	Ν	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	UC3856N	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF UC1856, UC2856, UC2856M, UC3856 :



- Catalog : UC3856, UC2856
- Automotive : UC2856-Q1, UC2856-Q1
- Military : UC2856M, UC1856
- Space : UC1856-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application



Texas

NSTRUMENTS

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#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UC2856DWTR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
UC3856DWTR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1



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## PACKAGE MATERIALS INFORMATION

9-Aug-2022



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UC2856DWTR	SOIC	DW	16	2000	356.0	356.0	35.0
UC3856DWTR	SOIC	DW	16	2000	356.0	356.0	35.0

### TEXAS INSTRUMENTS

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### TUBE



### - B - Alignment groove width

*All dimensions	are nominal
-----------------	-------------

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
5962-9453001M2A	FK	LCCC	20	1	506.98	12.06	2030	NA
UC1856L20	FK	LCCC	20	1	506.98	12.06	2030	NA
UC1856L20883B	FK	LCCC	20	1	506.98	12.06	2030	NA
UC2856DW	DW	SOIC	16	40	507	12.83	5080	6.6
UC2856DWG4	DW	SOIC	16	40	507	12.83	5080	6.6
UC2856N	N	PDIP	16	25	506	13.97	11230	4.32
UC3856DW	DW	SOIC	16	40	507	12.83	5080	6.6
UC3856N	N	PDIP	16	25	506	13.97	11230	4.32
UC3856NG4	N	PDIP	16	25	506	13.97	11230	4.32

LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N\*\*) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



### **DW 16**

# **GENERIC PACKAGE VIEW**

### SOIC - 2.65 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

7.5 x 10.3, 1.27 mm pitch

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





# **DW0016A**



## **PACKAGE OUTLINE**

SOIC - 2.65 mm max height

SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  This drawing is subject to change without notice.
  This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
- 5. Reference JEDEC registration MS-013.



# DW0016A

# **EXAMPLE BOARD LAYOUT**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## DW0016A

# **EXAMPLE STENCIL DESIGN**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

### N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



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